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Kind regards,

Team Nexperia



2 A ultra low V_F MEGA Schottky barrier rectifier Rev. 04 — 30 December 2008 Pr

Product data sheet

1. **Product profile**

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in SOD323 (SC-76) very small Surface-Mounted Device (SMD) plastic package.

1.2 Features

- Forward current: $I_F \le 2 A$
- Reverse voltage: V_R ≤ 10 V
- Ultra low forward voltage
- Very small SMD plastic package

1.3 Applications

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch Mode Power Supply (SMPS)
- Reverse polarity protection
- Low power consumption applications

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _F	forward current	$T_{sp} \le 55 \ ^{\circ}C$	-	-	2	А
V _R	reverse voltage		-	-	10	V
V _F	forward voltage	I _F = 1 A	<u>[1]</u> _	280	350	mV



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2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	e Graphic symbol
1	cathode	<u>[1]</u>	84
2	anode		1 - 2
			sym001

[1] The marking bar indicates the cathode.

3. Ordering information

Table 3. Orderi	ng informati	on	
Type number	Package		
	Name	Description	Version
PMEG1020EA	SC-76	plastic surface-mounted package; 2 leads	SOD323

4. Marking

Table 4.	Marking codes	
Type num	ber	Marking code
PMEG1020	DEA	E2

5. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		0 7 (,		
Symbol	Parameter	Conditions	Min	Max	Unit
V _R	reverse voltage		-	10	V
I _F	forward current	$T_{sp} \le 55 \ ^{\circ}C$	-	2	А
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ ms}; \delta \le 0.5$	-	3.2	A
I _{FSM}	non-repetitive peak forward current	square wave; t _p = 8 ms	-	9	A
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

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6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	<u>[1]</u> -	-	450	K/W
	junction to ambient		[2] _	-	210	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		<u>[3]</u> _	-	90	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB with copper clad 10×10 mm.

[3] Soldering point of cathode tab.

7. Characteristics

Table 7. Characteristics

$T_{amb} = 25 \circ C$ unless otherwise specified.

	•					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage		<u>[1]</u>			
		I _F = 0.01 A	-	100	130	mV
		I _F = 0.1 A	-	170	200	mV
		I _F = 1 A	-	280	350	mV
		I _F = 2 A	-	350	460	mV
I _R	reverse current		[2]			
		$V_R = 5 V$	-	0.7	2	mA
		V _R = 8 V	-	1	2.5	mA
		V _R = 10 V	-	1.2	3	mA
C _d	diode capacitance	$V_R = 5 V; f = 1 MHz$	-	37	45	pF

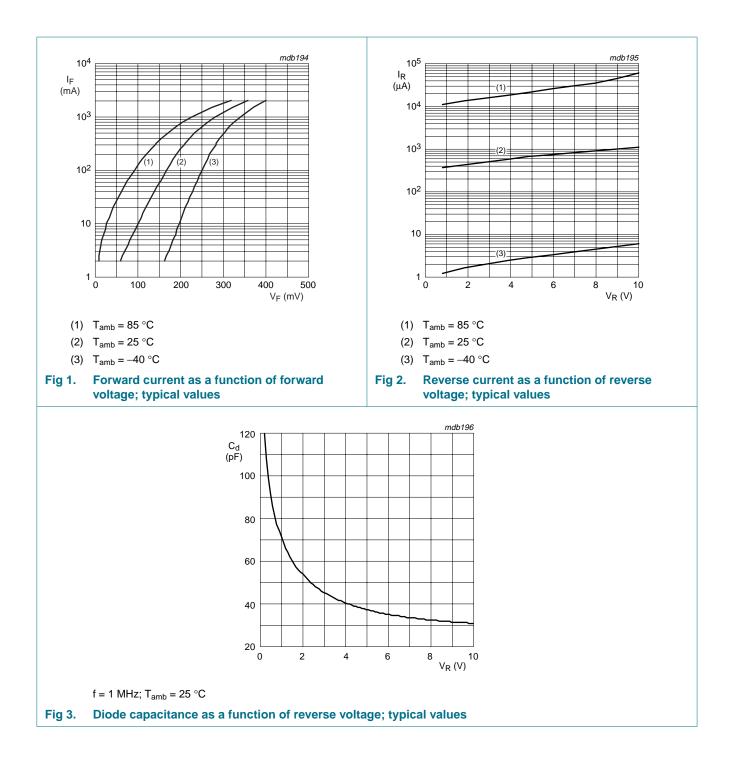
[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$.

[2] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

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PMEG1020EA

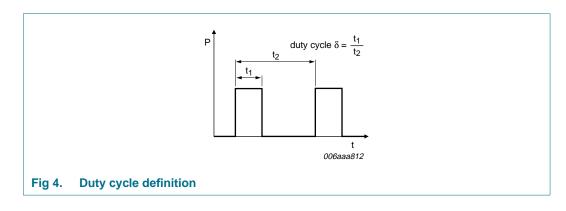
2 A ultra low V_F MEGA Schottky barrier rectifier



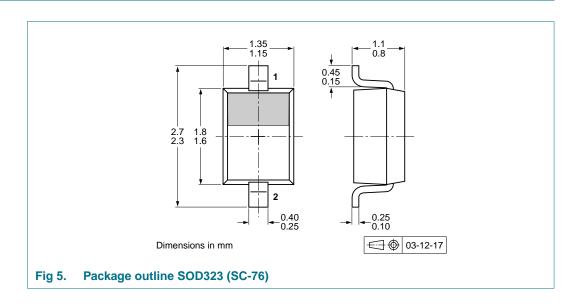
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8. Test information



9. Package outline



10. Packing information

Table 8. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

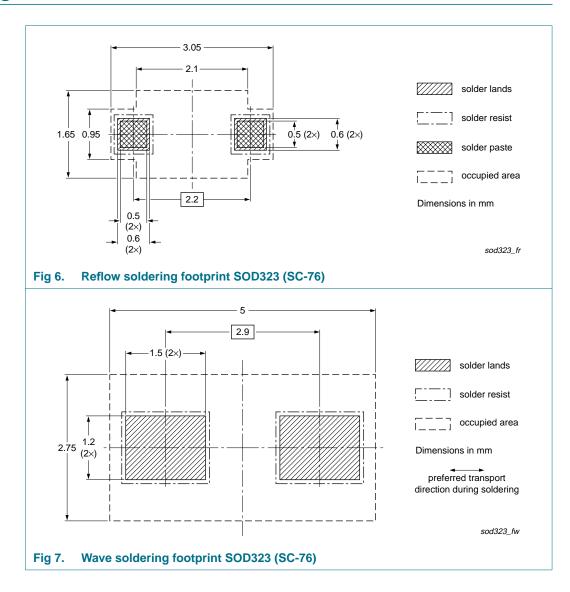
Type number	Package	Description	Packing c	uantity
			3000	10000
PMEG1020EA	SOD323	4 mm pitch, 8 mm tape and reel	-115	-135

[1] For further information and the availability of packing methods, see <u>Section 14</u>.

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11. Soldering



2 A ultra low V_F MEGA Schottky barrier rectifier

12. Revision history

Table 9. Revision histor	ory			
Document ID	Release date	Data sheet status	Change notice	Supersedes
PMEG1020EA_4	20081230	Product data sheet	-	PMEG1020EA_3
Modifications:		f this data sheet has been rede NXP Semiconductors.	esigned to comply w	ith the new identity
	 Legal texts h 	ave been adapted to the new o	company name wher	e appropriate.
	 Section 13 "L 	egal information": updated		
PMEG1020EA_3	20040206	Product specification	-	PMEG1020EA_2
PMEG1020EA_2	20030715	Product specification	-	PMEG1020EA_1
PMEG1020EA_1	20030307	Preliminary specification	-	-

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13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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PMEG1020EA_4
Product data sheet

NXP Semiconductors

PMEG1020EA

2 A ultra low V_F MEGA Schottky barrier rectifier

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